

In re Application of: Tadatoma et al.
 Application No. 09/787,502
 Filed: March 16, 2001
 For: SEMICONDUCTOR LIGHT RECEIVING ELEMENT

PATENT
 Attorney Docket No. 210013
 Date: March 4, 2002

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 ORIGINALLY FILED

COMMISSIONER OF PATENTS AND TRADEMARKS
 Washington, D.C. 20231

Sir:

Transmitted herewith is a Response to Office Action in the subject application.

☐ Applicant claims small entity status of this application under 37 C.F.R. § 1.27

☒ Petition For Extension Of Time

- ☐ Applicant(s) petitions for a extension of time under 37 C.F.R. § 1.136, the fee for which is \$890.00 (enclosed).
☒ Applicant(s) believes that no petition for an extension of time is necessary. However, to the extent that such petition is deemed necessary, applicant(s) hereby petition for a sufficient extension of time to render the present submission timely. Please charge Deposit Account No. 12-1216 for the appropriate petition fee.

☒ No additional claim fee is required.

☒ Other: English Translation of Japanese Patent Application Nos. 10-265516 and 10-265506 both filed on September 18, 1998.

The claim fee has been calculated as shown below:

					SMALL ENTITY		OTHER THAN A SMALL ENTITY	
	CLAIMS REMAINING AFTER AMENDMENT		HIGHEST NUMBER PREVIOUSLY PAID FOR	EXTRA CLAIMS PRESENT	RATE	ADDIT. CLAIM FEE	RATE	ADDIT. CLAIM FEE
TOTAL	11	MINUS	20	=0	x 9=	\$0.00	x 18=	\$0.00
INDEPENDENT	2	MINUS	3	=0	x 40=	\$0.00	x 80=	\$0.00
<input type="checkbox"/>	FIRST PRESENTATION OF MULTIPLE CLAIM				+ 130=	\$0.00	+ 260=	\$0.00
					TOTAL	\$0.00	TOTAL	\$0.00

☐ Please charge my Deposit Account No. 12-1216 in the amount of \$ 0.00. A duplicate copy of this sheet is attached.

☐ A check in the amount of \$0.00 is attached.

☒ The Commissioner is hereby authorized to charge payment of the following fees associated with this communication or credit any overpayment to Deposit Account No. 12-1216. A duplicate copy of this sheet is attached.

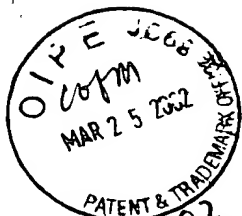
- ☒ Any filing fees under 37 C.F.R. § 1.16 for the presentation of extra claims.
☒ Any patent application processing fees under 37 C.F.R. § 1.17.

Respectfully submitted,

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PATENT
Attorney Docket No. 210013

51A
4-15-02
R. Gales

3-4-02 IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

Tadatomo et al.

Application No. 09/787,502

Art Unit: 2815

Examiner: E. Ortiz

Filed: March 16, 2001

For: SEMICONDUCTOR LIGHT
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RESPONSE TO OFFICE ACTION

Commissioner for Patents
Washington, D.C. 20231

Dear Sir:

In response to the Office Action dated December 3, 2001, please enter the following amendments and consider the following remarks.

AMENDMENTS

IN THE CLAIMS:

Please cancel claim 1.

Please amend claims 2 and 8 to read as follows:

2. (Amended) A semiconductor light receiving element comprising a light receiving layer comprising a GaN group semiconductor and an electrode formed on one surface of the light receiving layer as a light receiving surface in such a manner that the light can enter the light receiving layer, wherein the light receiving element is a Schottky barrier type light receiving element, said light receiving layer is a first conductivity type layer, said electrode formed on said light receiving surface comprises at least a Schottky electrode, and a total of boundary lines between areas of the light receiving surface covered with the Schottky electrode and exposed areas is longer than the length of the outer periphery of the light receiving surface.

8. (Amended) A semiconductor light receiving element comprising a light receiving layer comprising a GaN group semiconductor and an electrode formed on one surface of the light receiving layer as a light receiving surface in such a manner that the light can enter the